



SS52B THRU SS5200B

VOLTAGE RANGE 20 to 200 Volts
CURRENT 5.0 Ampere

Features

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 260 C/10 seconds at terminals



Mechanical Data

- Case: Transfer molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead :Solder plated, solderable per MIL-STD-750 method 2026
- Polarity: Color band denotes cathode end
- Weight: 0.003ounce, 0.093 gram

DO-214AA (SMB J-Bend)

Maximum Ratings and Electrical Characteristics

- Ratings at 25°C ambient temperature unless otherwise specified
- Single phase, half wave, 60Hz, resistive or inductive load
- For capacitive load derate current by 20%

TYPE NUMBER		SYMBOL S	SS 52B	SS 54B	SS 55B	SS 56B	SS 58B	SS 5100B	SS 5150B	SS 5200B	UNIT
Maximum Repetitive Peak Reverse Voltage		V _{RRM}	20	40	50	60	80	100	150	200	Volts
Maximum RMS Voltage		V _{RMS}	14	28	35	42	56	70	105	140	Volts
Maximum DC Blocking Voltage		V _{DC}	20	40	50	60	80	100	150	200	Volts
Maximum Average Forward Rectified Current at T _L see figure 1 T _L =100°C		I _(AV)	5.0								Amps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		I _{FSM}	125								Amps
Maximum Instantaneous Forward Voltage @ 5.0A(Note1)		V _F	0.55		0.70		0.85		0.90		Volts
Maximum DC Reverse Current at rated DC Blocking Voltage per element	T _A = 25°C	I _R	0.1						0.01		mA
	T _A = 100°C		20.0				10.0		2.0		
Typical Thermal Resistance (Note 2)		R _{θJA}	50								°C/W
		R _{θJL}	12								
Diode junction capacitance (Note 3)		C _J	300		200						pF
Operating Junction Temperature		T _J	(-55 to +150)						(-65 to +175)		°C
Storage Temperature Range		T _{STG}	(-55 to +150)								°C

Notes:

1. Pulse test: 300 μ s pulse width, 1% duty cycle.
2. Thermal resistance from Junction to ambient and from junction to lead mounted on PCB. with 0.3 $\times$ 0.3"(8.0 $\times$ 8.0mm) copper pad areas.
3. f=1MHz and applied 4V DC reverse voltage.



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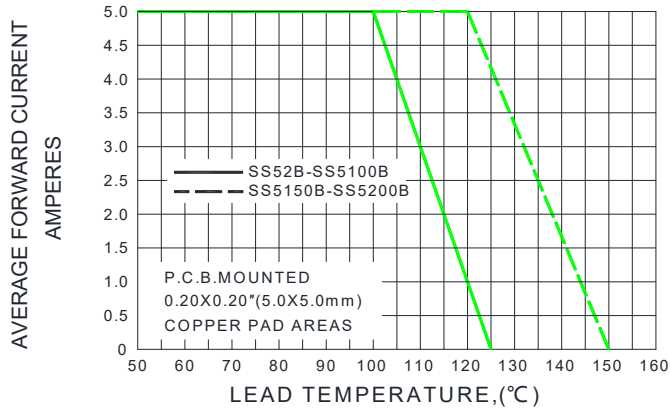
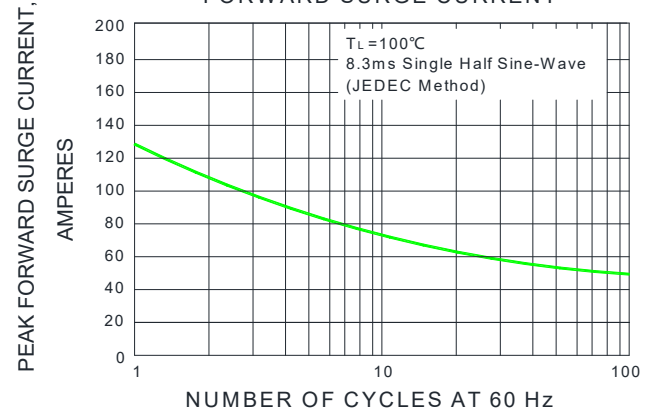
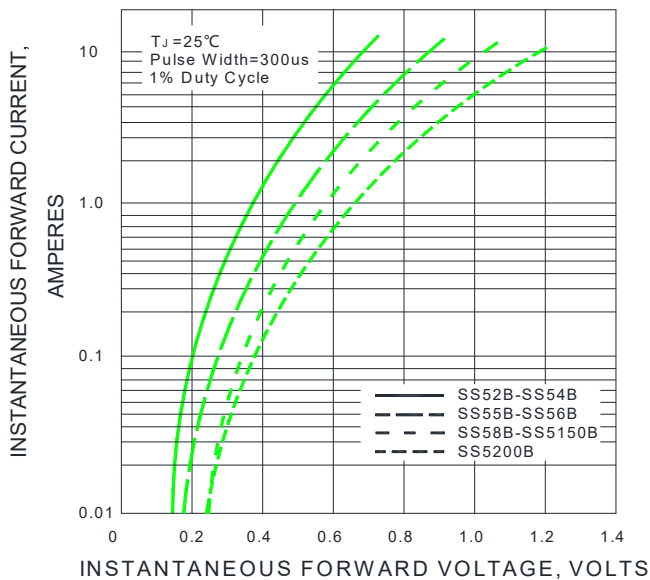
Ratings and Characteristic Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)FIG.1-FORWARD CURRENT
DERATING CURVEFIG.2-MAXIMUM NON-REPETITIVE PEAK
FORWARD SURGE CURRENTFIG.3-TYPICAL INSTANTANEOUS
FORWARD CHARACTERISTICS

FIG.4-TYPICAL REVERSE CHARACTERISTICS

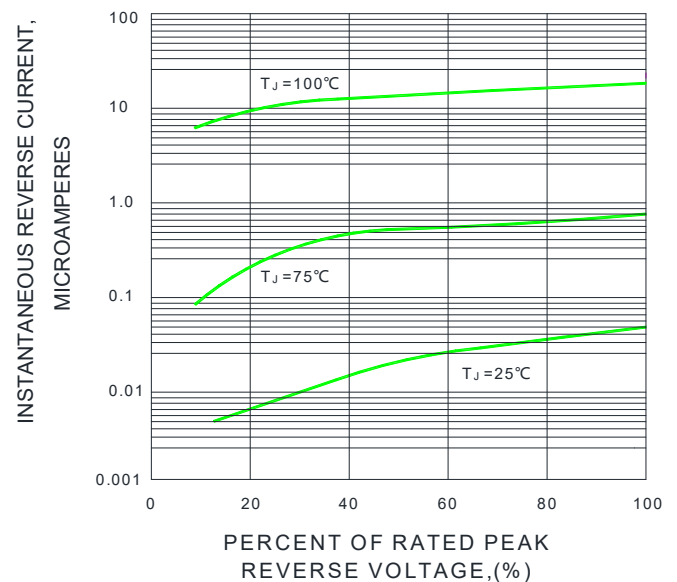
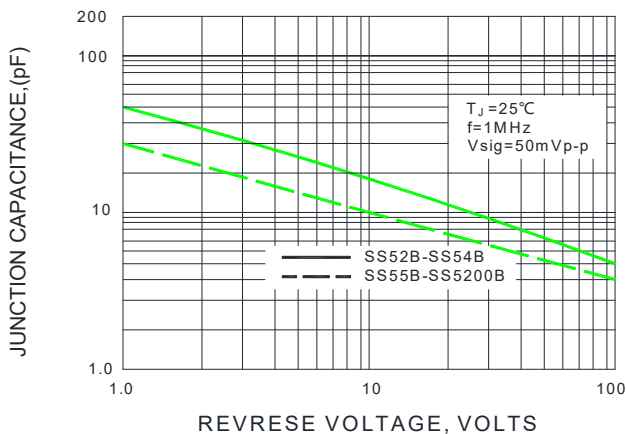


FIG.5-TYPICAL JUNCTION CAPACITANCE



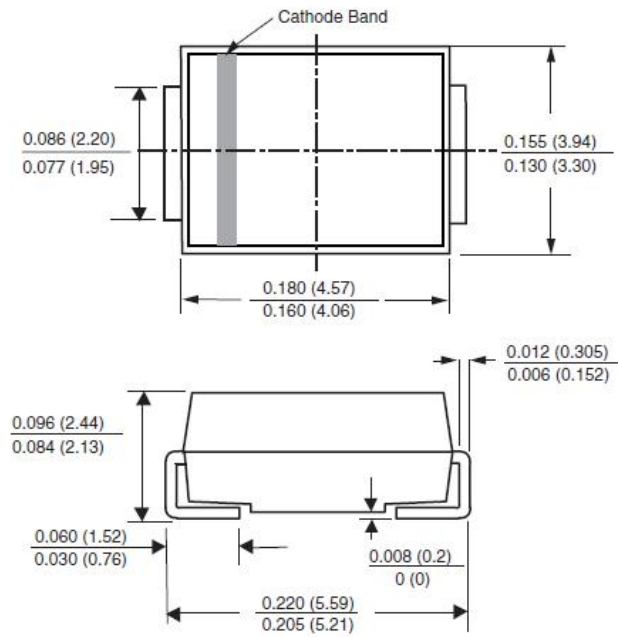


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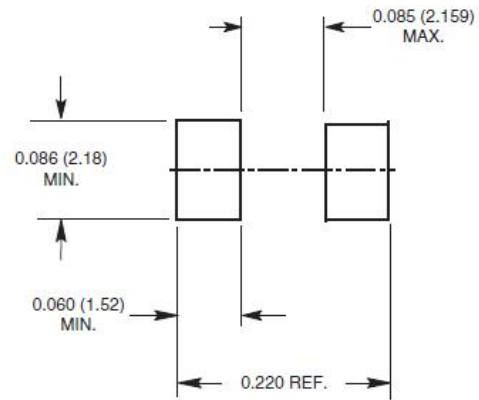
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Package Outline Dimensions in inches (millimeters)

DO-214AA (SMB-J-Bend)



Mounting Pad Layout

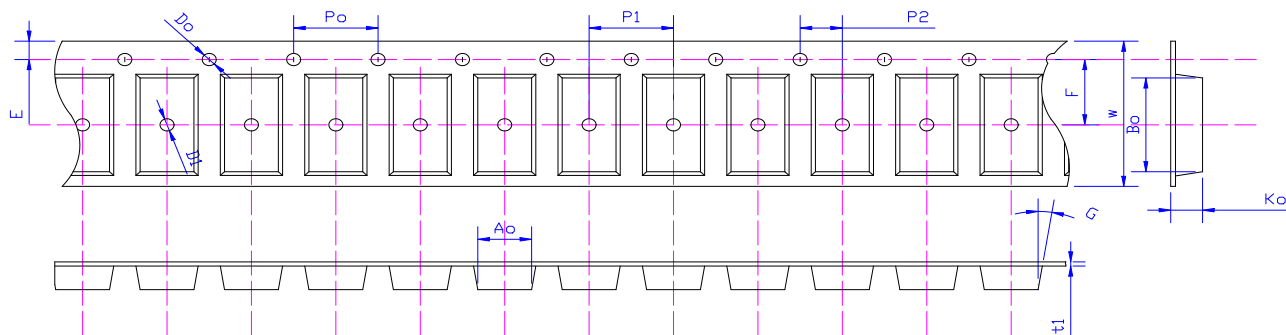




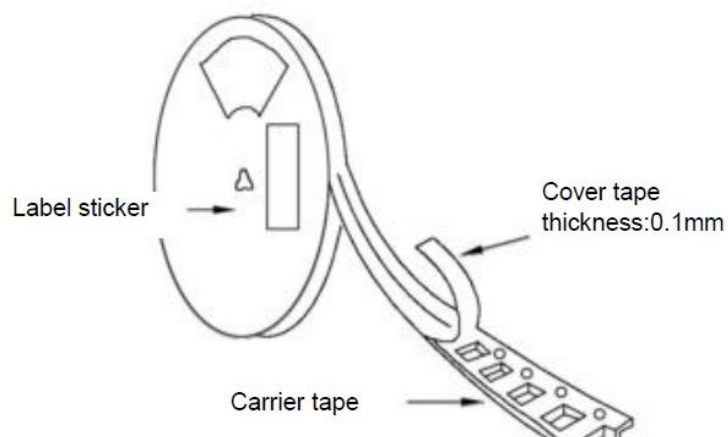
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Package Reel Information



Specifications	Ao	Bo	Ko	Po	W	t1
SMB	3.77±0.10	5.70±0.10	2.67±0.10	4.00±0.1	12.0±0.05	0.23±0.02



DEVICE TYPE	Tape Width	13"Reel			07"Reel			
		Q'TY/REEL(pcs)	BOX/CARTON	Q'TY/CARTON(pcs)	Q'TY/REEL(pcs)	REEL/BOX	BOX/CARTON	Q'TY/CARTON(pcs)
SMB	12mm	3000	8	48000	NA	NA	NA	NA



SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

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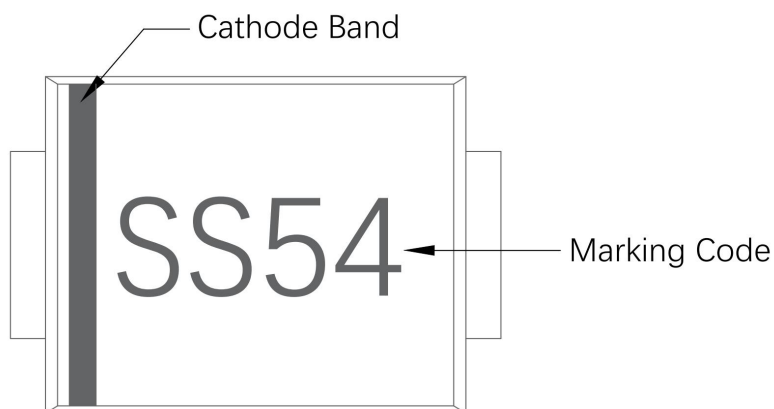
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Marking Code

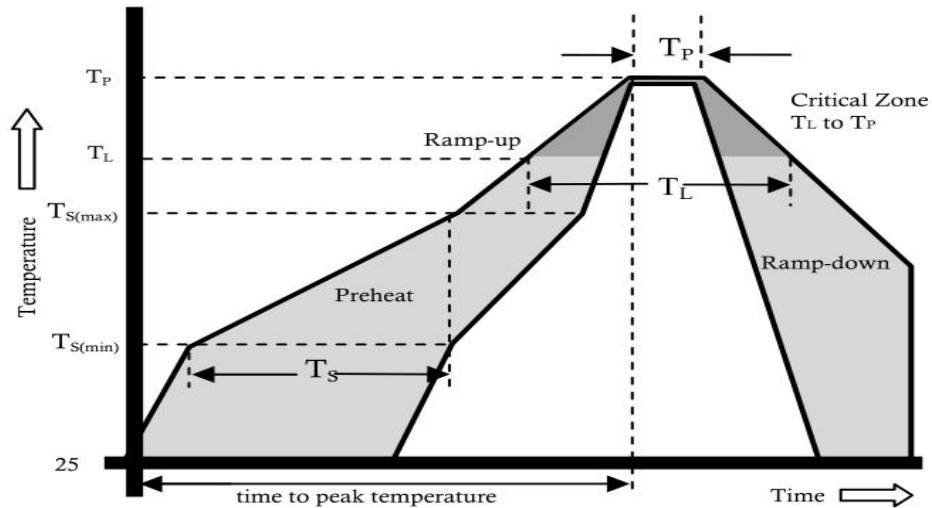


Part Number Code





Reflow Profile



Reflow Condition		Pb-Free Assembly
Pre Heat	Temperature Min.	+150°C
	Temperature Max.	+200°C
	Time(Min to Max)	60-180 secs.
Average ramp up rate(Liquidus Temp(T_L) to peak)		3°C/sec. Max.
$T_{S(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max.
Reflow	Temperature (T_L)(Liquidus)	+217°C
	Temperature (T_L)	60-150 secs.
Peak Temp (T_P)		+(260+0/-5)°C
Time within 5°C of actual Peak Temp (T_P)		25 secs.
Ramp-down Rate		6°C/sec. Max.
Time 25°C to peak Temp (T_P)		8 min. Max.
Do not exceed		+260°C